

25A, 35V - 150V Schottky Barrier Surface Mount Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- · High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

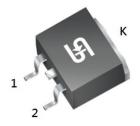
- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS					
PARAMETER VALUE UN					
I _F	25	Α			
V_{RRM}	35 - 150	V			
I _{FSM}	200	Α			
T _{J MAX}	150	°C			
Package	TO-263AB (D ² PAK)				
Configuration	Dual dies				

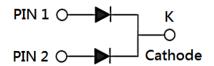








TO-263AB (D²PAK)



ABSOLUTE MAXIMUM R	ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)								
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	2535	2545	2550	2560	2590	25100	25150	UNIT
		CT	CT	СТ	СТ	СТ	CT	СТ	
Marking code on the device		MBRS 2535CT	MBRS 2545CT	MBRS 2550CT	MBRS 2560CT	MBRS 2590CT	MBRS 25100CT	MBRS 25150CT	
Repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	٧
Reverse voltage, total rms value	$V_{R(RMS)}$	24	31	35	42	63	70	105	٧
Forward current	I _F		25						Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}		200						Α
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		1 0.5						Α
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	25				А			
Critical rate of rise of off- state voltage	dv/dt				10,000)			V/µs

Notes:

1. $tp = 2.0\mu s$, 1.0KHz



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MBRS 2535 CT	MBRS 2545 CT	MBRS 2550 CT	MBRS 2560 CT	MBRS 2590 CT	MBRS 25100 CT	MBRS 25150 CT	UNIT
Junction temperature	T_J	-55 to +150					°C		
Storage temperature	T _{STG}		-55 to +150				°C		

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	R _{eJC}	1	°C/W

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRS2535CT MBRS2545CT MBRS2550CT MBRS2560CT MBRS2560CT I _F = 12.5A, T _J = 25°C			-	0.65	V
			-	0.75	٧	
	MBRS2590CT MBRS25100CT	i _F = 12.67 i _f 1.j = 20 0		-	0.85	V
	MBRS25150CT			-	0.95	V
	MBRS2535CT MBRS2545CT		-	0.82	V	
Forward voltage per diode ⁽¹⁾	MBRS2550CT MBRS2560CT	I _F = 25.0A, T _J = 25°C	V _F	-	0.90	V
	MBRS2590CT MBRS25100CT			-	0.92	V
	MBRS25150CT			-	1.02	V
	MBRS2535CT MBRS2545CT	I _F = 12.5A, T _J = 125°C		-	0.55	V
	MBRS2550CT MBRS2560CT			-	0.65	V
	MBRS2590CT MBRS25100CT			-	0.75	V
	MBRS25150CT			-	0.92	V
	MBRS2535CT MBRS2545CT			-	0.73	V
	MBRS2550CT MBRS2560CT	I _F = 25.0A, T _J = 125°C		-	0.80	V
	MBRS2590CT MBRS25100CT			-	0.88	V
	MBRS25150CT			-	0.98	V



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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)							
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT	
Reverse current @ rated V _R per diode ⁽²⁾ MBRS25150CT MBRS2535CT MBRS2545CT MBRS2550CT MBRS2560CT MBRS2590CT	T _J = 25°C		-	200	μΑ		
	MBRS2590CT MBRS25100CT MBRS25150CT		l _R	-	100	μΑ	
	MBRS2535CT MBRS2545CT	T _J = 125°C		-	15	mA	
	MBRS2550CT MBRS2560CT			-	10	mA	
	MBRS2590CT MBRS25100CT			-	7.5	mA	
	MBRS25150CT			-	5	mA	

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE(1)	PACKAGE	PACKING
MBRS25xCT	TO-263AB (D ² PAK)	800 / Tape & Reel

Notes:

1. "x" defines voltage from 35V(MBRS2535CT) to 150V(MBRS25150CT)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

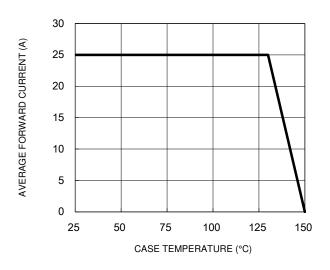


Fig.3 Typical Reverse Characteristics

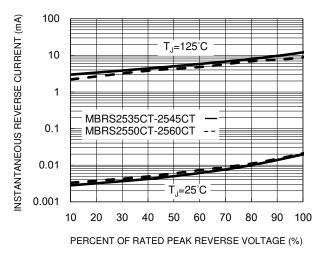


Fig.5 Typical Reverse Characteristics

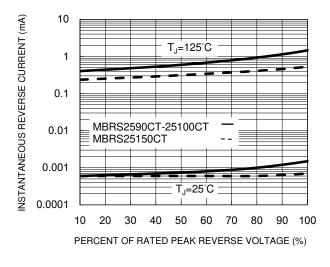


Fig.2 Typical Junction Capacitance

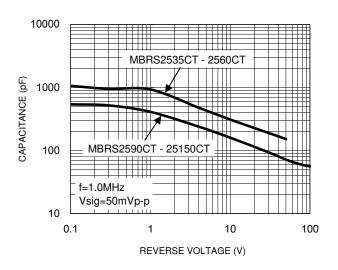


Fig.4 Typical Forward Characteristics

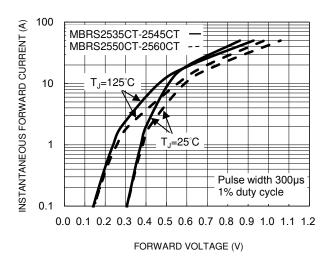
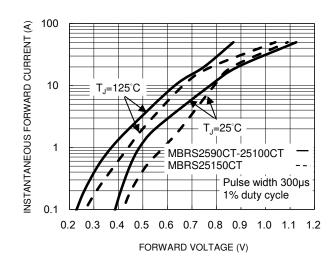


Fig.6 Typical Forward Characteristics





CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.7 Maximum Non-Repetitive Forward Surge Current

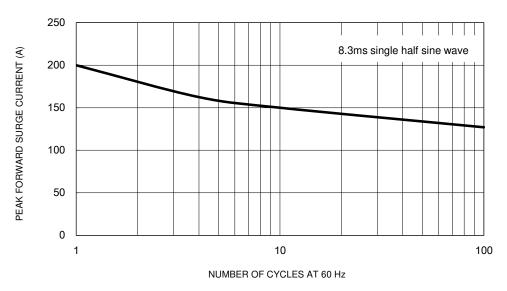
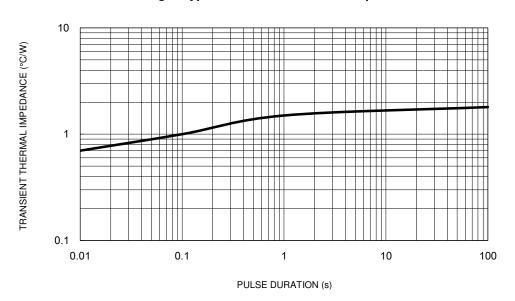


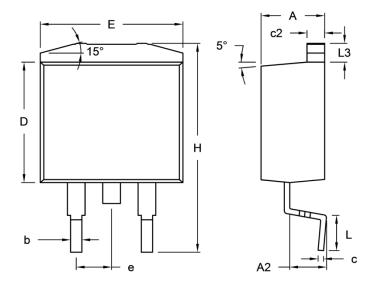
Fig.8 Typical Transient Thermal Impedance





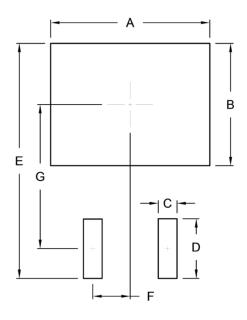
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM	DIM. Unit (mm)			(inch)	
DIN.	Min.	Max.	Min.	Max.	
Α	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
С	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
Н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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